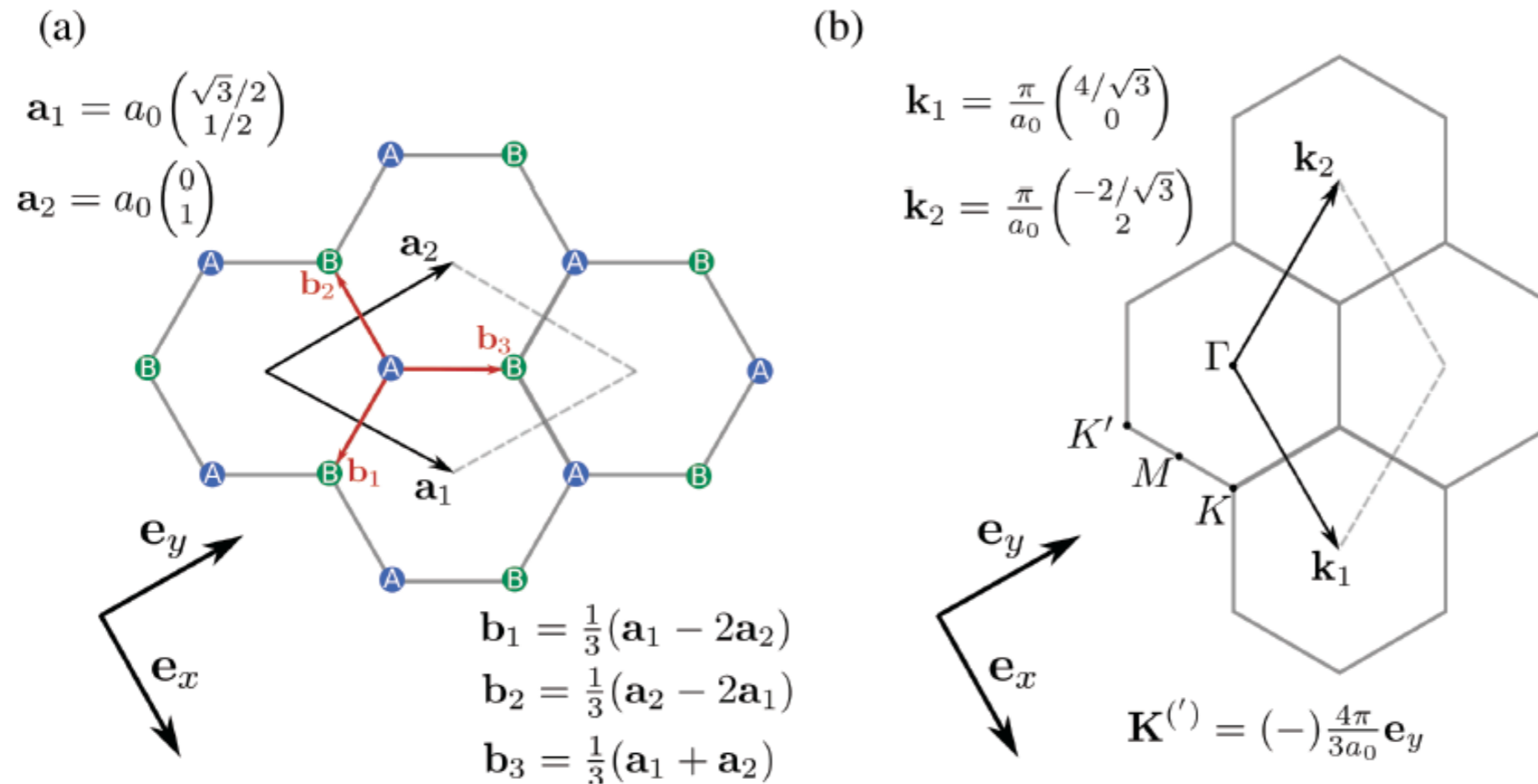


# Graphene: lattice structure, tight-binding, and all that...



**Figure 2.1.:** (a) Honeycomb structure of the graphene lattice. The unit cell, defined by the two lattice vectors  $\mathbf{a}_1$  and  $\mathbf{a}_2$ , contains two atoms, which constitute two equivalent sublattices A and B. Furthermore, the nearest neighbor vectors directed from an A-atom to the nearest B-atoms are depicted. (b) Brillouin zone of graphene defined by the reciprocal lattice vectors  $\mathbf{k}_1$  and  $\mathbf{k}_2$  containing the high symmetry points  $\Gamma$ ,  $M$ ,  $K$  and  $K'$ .

the electronic wave function  $\Psi(\mathbf{k})$  can be approximated within a tight-binding ansatz as a linear combination of both equivalent sublattices  $A$  and  $B$

$$\Psi_{\mathbf{k}}(\mathbf{r}) = c_A(\mathbf{k})\Phi_{A,\mathbf{k}}(\mathbf{r}) + c_B(\mathbf{k})\Phi_{B,\mathbf{k}}(\mathbf{r}), \quad (2.8)$$

where  $c_l(\mathbf{k})$  are the tight-binding coefficients and  $\Phi_{l,\mathbf{k}}(\mathbf{r})$  is the sublattice wave function with  $l = A, B$  [48, 51]. The latter is normalized and periodic on the respective sublattice  $\mathbf{R}_l$ , reading

$$\Phi_{l,\mathbf{k}}(\mathbf{r}) = \frac{1}{\sqrt{N}} \sum_{\mathbf{R}_l} e^{i\mathbf{k}\cdot\mathbf{R}_l} \phi(\mathbf{r} - \mathbf{R}_l), \quad (2.9)$$

where  $N$  is the number of unit cells in the system and  $\phi(\mathbf{r})$  is the atomic  $2p_z$  orbital. With this ansatz the Schrödinger equation

$$H\Psi_{\mathbf{k}}(\mathbf{r}) = \varepsilon_{\mathbf{k}}\Psi_{\mathbf{k}}(\mathbf{r}) \quad (2.10)$$

can be solved analytically.

It remains to determine the matrix elements  $H_{ij}$  and  $S_{ij}$ , e.g.

$$H_{AB} = \frac{1}{N} \sum_{\mathbf{R}_A, \mathbf{R}_B} e^{i\mathbf{k}(\mathbf{R}_B - \mathbf{R}_A)} \langle \phi(\mathbf{r} - \mathbf{R}_A) | H | \phi(\mathbf{r} - \mathbf{R}_B) \rangle. \quad (2.14)$$

Due to the localization of the atomic orbital,  $H_{AB}$  can be treated within the nearest neighbor approximation<sup>1</sup> [52]. That means for each summand  $\mathbf{R}_A$  only the three adjacent  $B$  atoms at  $\mathbf{R}_{B_i} = \mathbf{R}_A + \mathbf{b}_i$  contribute, where the  $\mathbf{b}_i$  with  $i = 1, 2, 3$  are the nearest neighbor vectors, which are shown in Fig. 2.1(a). Note that the opposite case, i.e. fixing the B-sublattice and considering the nearest A-atoms, leads to the same eigenvalues. The three remaining integrals in Eq. (2.14)  $\gamma_0 = \langle \phi(\mathbf{r} - \mathbf{R}_A) | H | \phi(\mathbf{r} - \mathbf{R}_{B_i}) \rangle$  are independent on  $i$ , since the  $2p_z$ -orbital depends in the plane only on the distance  $\phi(\mathbf{r}_{\parallel}, z) \equiv \phi(|\mathbf{r}_{\parallel}|, z)$  [48]. Common values of the integral are in the range between  $-2.5 \text{ eV}$  and  $-3.0 \text{ eV}$  [48, 53], where throughout this work  $-2.84 \text{ eV}$  is applied, which is denoted by  $\gamma_0$  in the following. Therewith, Eq. (2.14) yields

$$H_{AB} = \gamma_0 e(\mathbf{k}), \quad (2.15)$$

where

$$e(\mathbf{k}) = \sum_{i=1}^3 e^{i\mathbf{k}\mathbf{b}_i} \quad (2.16)$$

is the nearest neighbor sum, which accounts for the graphene lattice symmetry. The other matrix elements can be treated in analogy, where  $H_{AA} = \epsilon_0$  is a constant, which is chosen to be  $0 \text{ eV}$  to benchmark the energy scale with respect to the intrinsic Fermi level  $\epsilon_F$ . The normalization of the sublattice wave function  $\Phi_{l,\mathbf{k}}(\mathbf{r})$  directly yields  $S_{AA} = 1$ . Finally,  $S_{AB}$  represents the overlap between neighboring orbitals and is given by  $S_{AB} = s_0 e(\mathbf{k})$ . The overlap integral  $s_0 = \langle \phi(\mathbf{r}) | \phi(\mathbf{r} - \mathbf{b}_1) \rangle$  can be evaluated numerically via the  $2p_z$  orbital. Common values of the overlap integral lie between  $0.06$  and  $0.13$ , depending on the applied effective charge  $Z^*$  [48, 54]. However, later the overlap integral will be neglected providing a good description in energy regime addressed in this work.

**Linear band approximation** Close to the Dirac point the tight-binding bandstructure can be linearly approximated. Therefore, the overlap integral  $\mathbf{s}_0$  is neglected and the nearest neighbor sum, Eq. (2.16), is expanded up to the first order around the  $K$  (or  $K'$ ) point

$$e(\mathbf{k}) \approx e(\mathbf{K}) + [\nabla_{\mathbf{k}} e(\mathbf{k})] \Big|_{\mathbf{k}=\mathbf{K}} (\mathbf{k} - \mathbf{K}) = -\frac{a_0 \sqrt{3}}{2} (i\tilde{k}_x + \tilde{k}_y), \quad (2.20)$$

where  $\mathbf{K} = \frac{4\pi}{3a_0} \mathbf{e}_y$  and  $\tilde{\mathbf{k}} = \mathbf{k} - \mathbf{K}$  is the electron wave vector with respect to the Dirac point [56]. In the following  $\tilde{\mathbf{k}}$  is denoted by  $\mathbf{k}$ , if the respective consideration is restricted to a Dirac valley.